

# DATA/AUDIO Low-Voltage Dual DPDT Analog Switch

# **FSA2466**

### **Description**

The FSA2466 is a dual Double–Pole, Double–Throw (DPDT) analog switch. The FSA2466 operates from a single 1.65 V to 4.45 V supply and features an ultra–low on resistance of 2  $\Omega$  at a +2.7 V supply and  $T_A$  =  $25^{\circ}C$ . This device is fabricated with sub–micron CMOS technology to achieve fast switching speeds and is designed for break–before–make operation.

FSA2466 features very low quiescent current even when the control voltage is lower than the  $V_{CC}$  supply. This allows mobile handset applications direct interface with the baseband processor general-purpose I/Os.

### **Features**

Switch Type	DPDT (2x)
Input Type	Data / Audio Switch
Input Signal Range	0 to V <sub>CC</sub>
V <sub>CC</sub>	1.65 to 4.45 V
R <sub>ON</sub>	2.5 $\Omega$ at 2.7 V
R <sub>FLAT</sub>	$0.8~\Omega$ at 2.7 V
ESD	8 kV HBM
Bandwidth	245 MHz
C <sub>ON</sub> at 240 MHz	16 pF
C <sub>OFF</sub> at 240 MHz	6.0 pF
Features	Low I <sub>CTT</sub>
Package	16-Lead UMLP 1.80 x 2.60 x 0.55 mm, 0.40 mm pitch
Top Mark	KA
Ordering Information	FSA2466UMX

### **Applications**

- MP3 Portable Media Players
- Cellular Phones, Smartphones



### **MARKING DIAGRAM**

KA&K &2&Z

KA = Specific Device Code

K = 2-Digits Lot Run Traceability Code

&2 = 2-Digit Date Code

&Z = Assembly Plant Code

### ORDERING INFORMATION

See detailed ordering and shipping information on page 2 of this data sheet.

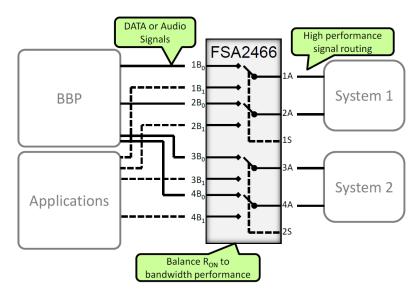


Figure 1. Typical Mobile Phone Application

### **ORDERING INFORMATION**

Part Number	Top Mark	Operating Temperature Range	Package	Shipping <sup>†</sup>
FSA2466UMX	KA	−40 to 85°C	16-Lead, Quad, Ultrathin Molded Leadless Package (UMLP), 1.8 x 2.6 mm	5000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **Pin Configuration**

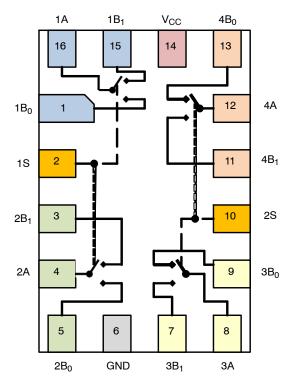


Figure 2. FSA2466UMX (Top View)

# **PIN DESCRIPTIONS**

Pin #	Name	Туре	Description						
1	1B0	I/O	Data / Audio Port						
2	18	Innut	Control Input for Data & Common Ports 1 & 2	0	1B <sub>0</sub> = 1A & 2B <sub>0</sub> = 2A				
2	13	Input	Control input for Data & Continion Ports 1 & 2		1B1 = 1A & 2B1 = 2A				
3	2B1	I/O	Data / Audio Port						
4	2A	I/O	Data / Audio Common Port						
5	2B0	I/O	Data / Audio Port						
6	GND	GND							
7	3B1	I/O	Data / Audio Port						
8	ЗА	I/O	Data / Audio Common Port						
9	3B0	I/O	Data / Audio Port						
10	2S	Control Institute Date 9 Common Date 9 9 4	Control Input for Data & Common Borto 2 & 4	0	3B0 = 3A & 4B0 = 4A				
10	23	Input	Control Input for Data & Common Ports 3 & 4	1	3B1 = 3A & 4B1 = 4A				
11	4B1	I/O	Data / Audio Port						
12	4A	I/O	Data / Audio Common Port						
13	4B0	I/O	Data / Audio Port						
14	Vcc	Supply	Voltage supply						
15	1B1	I/O	Data / Audio Port	Data / Audio Port					
16	1A	I/O	Data / Audio Common Port						

### **ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	Supply Voltage	-0.50	5.25	V	
Vs	Switch Voltage	Switch Voltage			
V <sub>IN</sub>	Input Voltage		-0.5	5.0	V
I <sub>IK</sub>	Input Diode Current	Input Diode Current			
I <sub>SW</sub>	Switch Current		350	mA	
I <sub>SWPEAK</sub>	Peak Switch Current (Pulsed at 1 ms Duration,		500	mA	
T <sub>STG</sub>	Storage Temperature Range		-65	+150	°C
TJ	Junction Temperature			+150	°C
TL	Lead Temperature, Soldering 10 seconds			+260	°C
ESD	Human Body Model, JESD22-A114	I/O to GND		8	kV
	Power to GND			8	
		All Other Pins		8	
	Charged Device Model, JEDEC: JESD22-C101	1		2	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Supply Voltage (Note 1)	1.65	4.45	V
V <sub>IN</sub>	Control Input Voltage (Note 2)	0	V <sub>CC</sub>	V
Vs	Switch Input Voltage	0	V <sub>CC</sub>	V
TA	Operating Temperature	-40	+85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

1. For 4.45 V operation, SEL frequency (pins 1S & 2S) should not exceed 100 Hz and 100 ns edge rate.

2. Unused inputs must be held HIGH or LOW. They may not float.

### DC ELECTRICAL CHARACTERISTICS

(Typical values are at  $T_A = 25^{\circ}C$  unless otherwise specified.)

				T <sub>A</sub> = +25°C			$T_A = -40 \text{ to } +85^{\circ}\text{C}$		
Symbol	Parameter	Condition	V <sub>CC</sub> (V)	Min.	Тур.	Max.	Min.	Max.	Unit
V <sub>IH</sub>	Input Voltage High		4.30				1.4		V
			2.70 to 3.60				1.3		
			2.30 to 2.70				1.1		
			1.65 to 1.95				0.9		
V <sub>IL</sub>	Input Voltage Low		4.30					0.7	V
			2.70 to 3.60					0.5	
		2.30 to 2.70					0.4		
			1.65 to 1.95					0.4	
I <sub>IN</sub>	Control Input Leakage	V <sub>IN</sub> = 0 V to V <sub>CC</sub>	1.65 to 4.30				-0.5	0.5	μΑ
	Off Leakage Current of Port nBo and nB1	nA=0.3 V, V <sub>CC</sub> -0.3V	1.95 to 4.30	-10		10	-50	50	nA
		nB <sub>0</sub> or nB <sub>1</sub> =0.3 V, V <sub>CC</sub> -0.3V or Floating							
I <sub>A(ON)</sub>	On Leakage Current of Port A	nA = 0.3 V, V <sub>CC</sub> -0.3V	1.95 to 4.30	-10		10	-50	50	nA
		nB <sub>0</sub> or nB <sub>1</sub> = 0.3 V, $V_{CC}$ -0.3V or Floating							
R <sub>ON</sub>	Switch On Resistance	I <sub>OUT</sub> =100 mA	4.30		1.6			2.0	Ω
	(Note 3)	I <sub>OUT</sub> =100 mA, nB <sub>0</sub> or	2.70		2.0			2.5	
	nB1=0 V, 0.7 V, 1.2 V, V <sub>CC</sub>	2.30		2.2			2.7		
		I <sub>OUT</sub> =100mA, nB <sub>0</sub> or nB <sub>1</sub> =0.7 V	1.80		4.3			6.0	
$\Delta R_{ON}$	On Resistance Matching Between Channels (Note 4)	I <sub>OUT</sub> =100 mA, nB <sub>0</sub> or nB <sub>1</sub> =0.8 V	2.70		0.04			0.20	Ω
	(	I <sub>OUT</sub> =100 mA, nB <sub>0</sub> or nB <sub>1</sub> =0.7 V	2.30		0.03			0.30	
D	On Resistance Flatness	I <sub>OUT</sub> =100 mA, nB <sub>0</sub> or	2.70		0.60			0.8	Ω
R <sub>FLAT(ON)</sub>	(Note 5)	$nB1 = 0V \rightarrow V_{CC}$	2.30		0.75			0.9	52
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> =0 V to V <sub>CC</sub> , I <sub>OUT</sub> =0 V	4.30	-100		100	-500	500	nA
	Increase in L. Comment	V <sub>IN</sub> =1.8 V	4.30		7	12		15	
ICCT	Increase in I <sub>CC</sub> Current per Control Voltage	V <sub>IN</sub> =2.6 V	4.30		3	6		7	μΑ

<sup>3.</sup> On resistance is determined by the voltage drop between the A and B pins at the indicated current through the switch.

ΔR<sub>ON</sub>=R<sub>ON</sub> max – R<sub>ON</sub> min measured at identical V<sub>CC</sub>, temperature, and voltage.
 Flatness is defined as the difference between the maximum and minimum value of on resistance over the specified range of conditions.

# **AC ELECTRICAL CHARACTERISTICS**

(Typical values are at  $T_A$  = 25°C unless otherwise specified.)

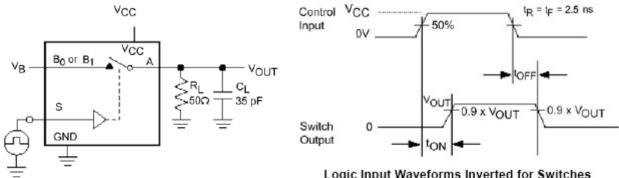
				7	Γ <sub>A</sub> = +25°	С	T <sub>A</sub> = -40	to +85°C		
Symbol	Parameter	Condition	V <sub>CC</sub>	Min.	Тур.	Max.	Min.	Max.	Unit	Figure
t <sub>ON</sub>	Turn-On Time	nB <sub>0</sub> or nB <sub>1</sub> =1.5 V R <sub>L</sub> =50 $\Omega$ , C <sub>L</sub> =35 pF	3.6 to 4.3			50		60	ns	Figure 3
			2.7 to 3.6			65		75		
			2.3 to 2.7			80		90		
t <sub>OFF</sub>	Turn-Off Time	nB0 or nB1=1.5 V	3.6 to 4.3			32		40	ns	Figure 3
		R <sub>L</sub> =50 $\Omega$ , C <sub>L</sub> =35 pF	2.7 to 3.6			42		50		
			2.3 to 2.7			52		60		
t <sub>BBM</sub>	Break-Before-	nB0 or nB1=1.5 V	3.6 to 4.3		15				ns	Figure 4
	Make Time (Note 6)	R <sub>L</sub> =50 Ω, C <sub>L</sub> =35 pF	2.7 to 3.6		15					
			2.3 to 2.7		15				7	
Q	Charge Injection	C <sub>L</sub> =100 pF, V <sub>GEN</sub> =0 V, R <sub>GEN</sub> =0 Ω	3.6 to 4.3		8				pC Fi	Figure 6
		C <sub>L</sub> =100 pF, V <sub>GEN</sub> =0 V, R <sub>GEN</sub> =0 Ω	2.7 to 3.6		6					
		C <sub>L</sub> =100 pF, V <sub>GEN</sub> =0 V, R <sub>GEN</sub> =0 Ω	2.3 to 2.7		3					
OIRR	Off Isolation	f=100 KHz, R <sub>L</sub> =50 Ω,	3.6 to 4.3		-90				dB	Figure 5
		C <sub>L</sub> =5 pF	2.7 to 3.6		-90					
			2.3 to 2.7		-90					
Xtalk	Crosstalk	f=100 KHz, R <sub>L</sub> =50 Ω,	3.6 to 4.3		-90				dB	Figure 5
		C <sub>L</sub> =5 pF	2.7 to 3.6		-90					
			2.3 to 2.7		-90					
BW	-3dB Bandwidth	R <sub>L</sub> =50 Ω	2.3 to 4.3		245				MHz	Figure 8
THD	Total Harmonic	$R_L=32 \Omega$ , $V_{IN}=2V_{PP}$ ,	3.6 to 4.3		0.21				%	Figure 9
	Distortion	f=20 to 20 kHz 2.7 to 3.6	2.7 to 3.6		0.17					
			2.3. to 2.7		0.26				7	
		R <sub>L</sub> =600 Ω, V <sub>IN</sub> =2 V <sub>PP</sub> ,	3.6 to 4.3		0.01					
		f=20 to 20 kHz	2.7 to 3.6		0.008					
			2.3. to 2.7		0.012					

<sup>6.</sup> Guaranteed by characterization, not production tested.

# **CAPACITANCE**

Symbol	Parameter	Condition	v <sub>cc</sub>	T <sub>A</sub> = +25°C Typical	Unit	Figure
C <sub>IN</sub>	Control Pin Input Capacitance	f = 1 MHz	0	1.3	pF	Figure 3
C <sub>OFF</sub>	B Port Off Capacitance	f = 1 MHz	3.3	6.0	ρF	Figure 3
OOFF	B Fort Oil Capacitance	f = 240 MHz	3.3	6.0	ы	r igure 5
Carr	A Port On Capacitance	f = 1 MHz	3.3	21.0	ρF	Figure 3
C <sub>ON</sub>	A Fort On Capacitance	f = 240 MHz	3.3	16.0	рі	Figure 3

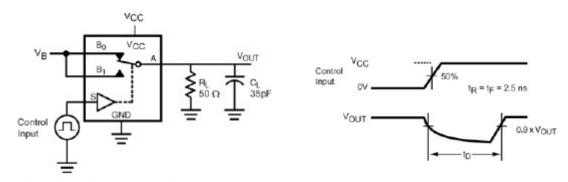
### **AC Loadings and Waveforms**



C<sub>L</sub> includes Fixture and Stray Capacitance

Logic Input Waveforms Inverted for Switches that have the Opposite Logic Sense

Figure 3. Turn-On / Turn-Off Timing



C<sub>L</sub> Includes Fixture and Stray Capacitance

Figure 4. Break-Before-Make Timing

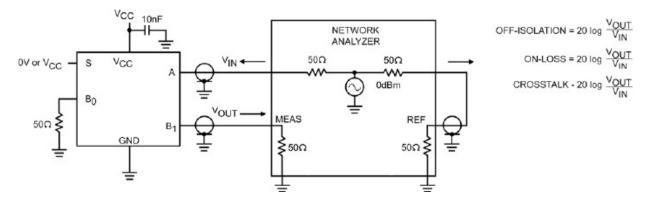


Figure 5. Off Isolation and Crosstalk

# AC Loadings and Waveforms (Continued)

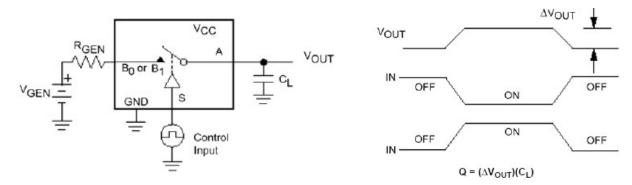


Figure 6. Charge Injection

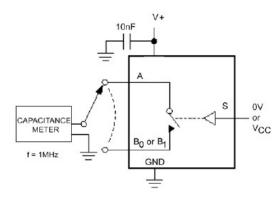


Figure 7. On / Off Capacitance Measurement Setup

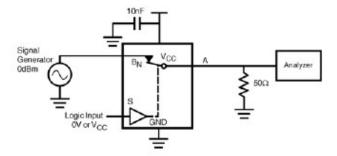


Figure 8. Bandwidth

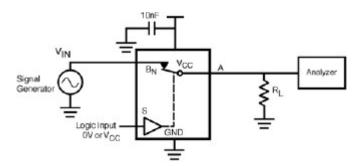
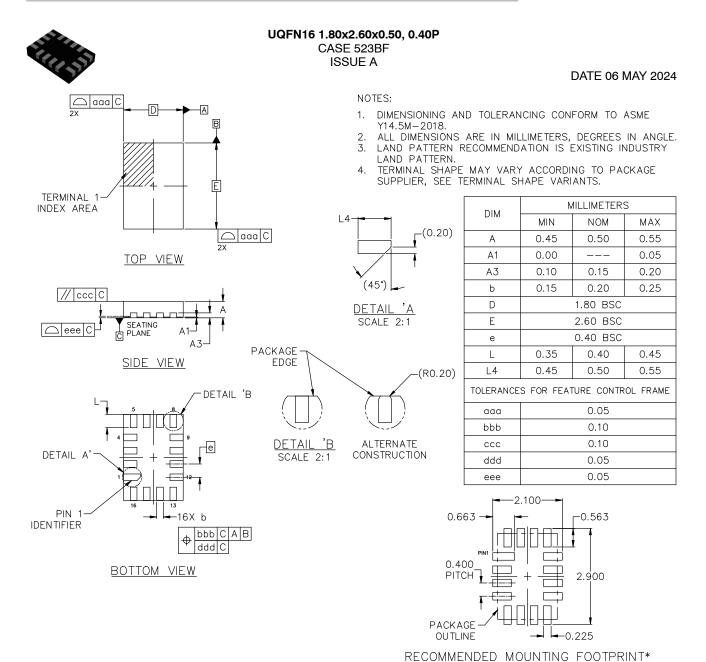


Figure 9. Harmonic Distortion





*FOR ADDITIONAL INFORMATION ON OUR Pb-FREE
STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD
THE ONSEMI SOLDERING AND MOUNTING TECHNIQUES
REFERENCE MANUAL, SOLDERRM/D.

DOCUMENT NUMBER:	98AON13709G	Electronic versions are uncontrolled except when accessed directly from Printed versions are uncontrolled except when stamped "CONTROLLED"	
DESCRIPTION:	UQFN16 1.80x2.60x0.50, 0	UQFN16 1.80x2.60x0.50, 0.40P	

onsemi and ONSemi are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.

onsemi, ONSEMI., and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <a href="www.onsemi.com/site/pdf/Patent-Marking.pdf">www.onsemi.com/site/pdf/Patent-Marking.pdf</a>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems. or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

 $\textbf{Technical Library:} \ \underline{www.onsemi.com/design/resources/technical-documentation}$ 

onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support

For additional information, please contact your local Sales Representative at

www.onsemi.com/support/sales